



SamHop Microelectronics Corp.



STS 2306E

Jan. 10 2008 Ver1.0

N-Channel Enhancement Mode Field Effect Transistor

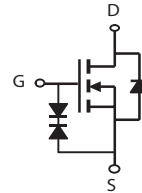
PRODUCT SUMMARY

V _{DS}	I _D	R _{DS(ON)} (m Ω) Max
20V	6.5A	30 @ V _{GS} = 4.5V 40 @ V _{GS} = 2.5V

FEATURES

- Super high dense cell design for low R_{DS(ON)}.
- Rugged and reliable.
- Surface Mount Package.
- ESD Protected.

SOT-23



ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±10	V
Drain Current-Continuous ^a @ T _J =25°C -Pulsed ^b	I _D	6.5	A
	I _{DM}	24	A
Drain-Source Diode Forward Current ^a	I _S	1.25	A
Maximum Power Dissipation ^a	P _D	1.25	W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 to 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient ^a	R θ JA	100	°C/W
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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ ^c	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =16V, V _{GS} =0V			1	uA
Gate-Body Leakage	I _{GSS}	V _{GS} =±10V, V _{DS} =0V			±10	uA
ON CHARACTERISTICS ^b						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D = 250uA	0.5	0.9	1.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D = 6 A		24	30	m ohm
		V _{GS} =2.5V, I _D = 3 A		32	40	m ohm
Forward Transconductance	g _{FS}	V _{DS} = 7V, I _D = 5A		16		S
DYNAMIC CHARACTERISTICS ^c						
Input Capacitance	C _{ISS}	V _{DS} =10V, V _{GS} = 0V f=1.0MHz		540		pF
Output Capacitance	C _{OSS}			160		pF
Reverse Transfer Capacitance	C _{RSS}			100		pF
SWITCHING CHARACTERISTICS ^c						
Turn-On Delay Time	t _{D(ON)}	V _{DD} = 10V, I _D = 1A, V _{GEN} = 4.5V, R _L = 10 ohm R _{GEN} = 10 ohm		15		ns
Rise Time	t _r			20		ns
Turn-Off Delay Time	t _{D(OFF)}			36		ns
Fall Time	t _f			11		ns
Total Gate Charge	Q _g	V _{DS} =10V, I _D =6A, V _{GS} =4.5V		6.4		nC
		V _{DS} =10V, I _D =6A, V _{GS} =2.5V		4.6		nC
Gate-Source Charge	Q _{gs}	V _{DS} =10V, I _D = 6 A V _{GS} =4.5V		1.1		nC
Gate-Drain Charge	Q _{gd}			2.8		nC

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ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ ^c	Max	Unit
DRAIN-SOURCE DIODE CHARACTERISTICS ^b						
Diode Forward Voltage	V_{SD}	$V_{GS} = 0\text{V}, I_S = 1.25\text{A}$		0.76	1.2	V

Notes

- a. Surface Mounted on FR4 Board, $t \leq 10\text{sec}$.
- b. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
- c. Guaranteed by design, not subject to production testing.

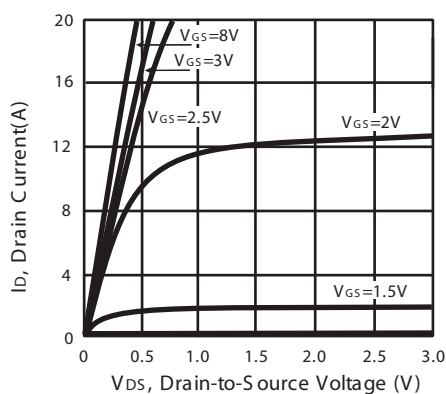


Figure 1. Output Characteristics

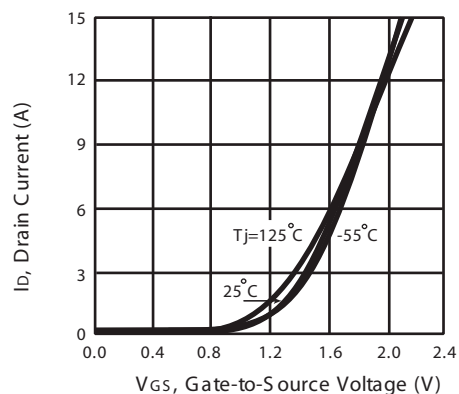


Figure 2. Transfer Characteristics

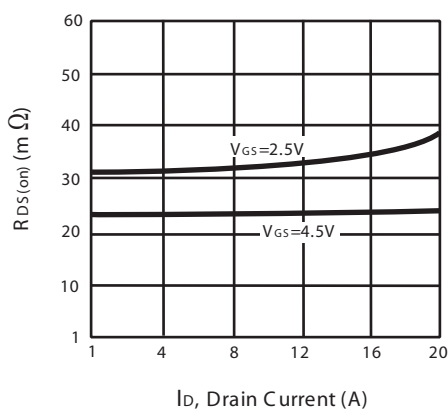


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

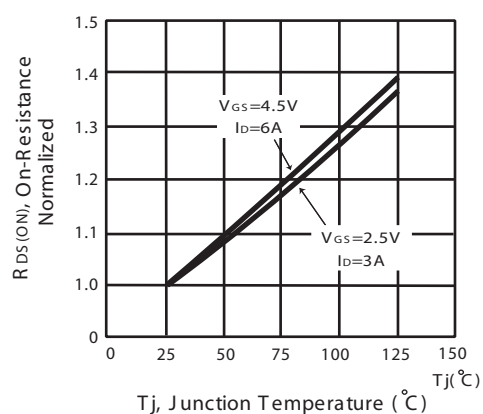


Figure 4. On-Resistance Variation with Drain Current and Temperature

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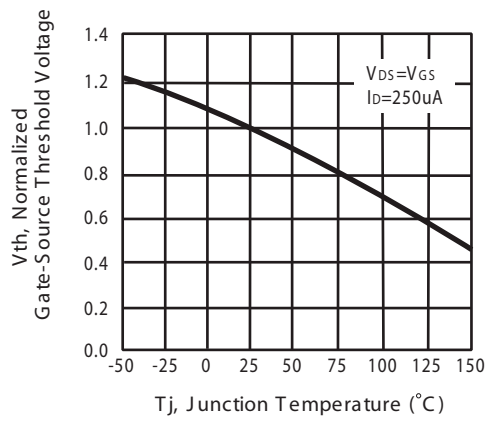


Figure 5. Gate Threshold Variation with Temperature

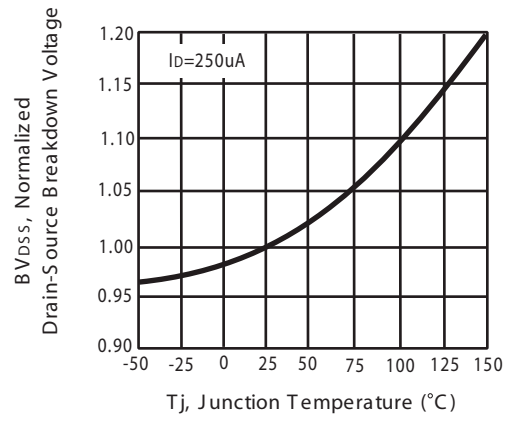


Figure 6. Breakdown Voltage Variation with Temperature

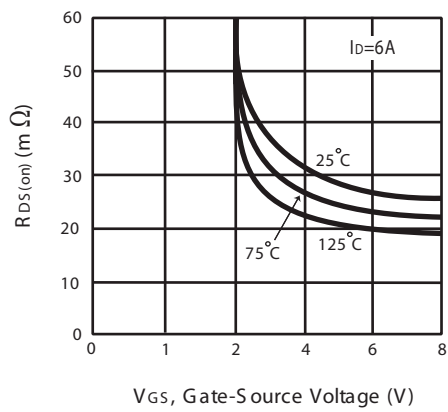


Figure 7. On-Resistance vs. Gate-Source Voltage

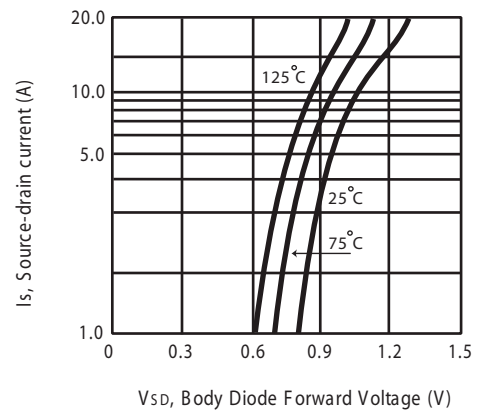
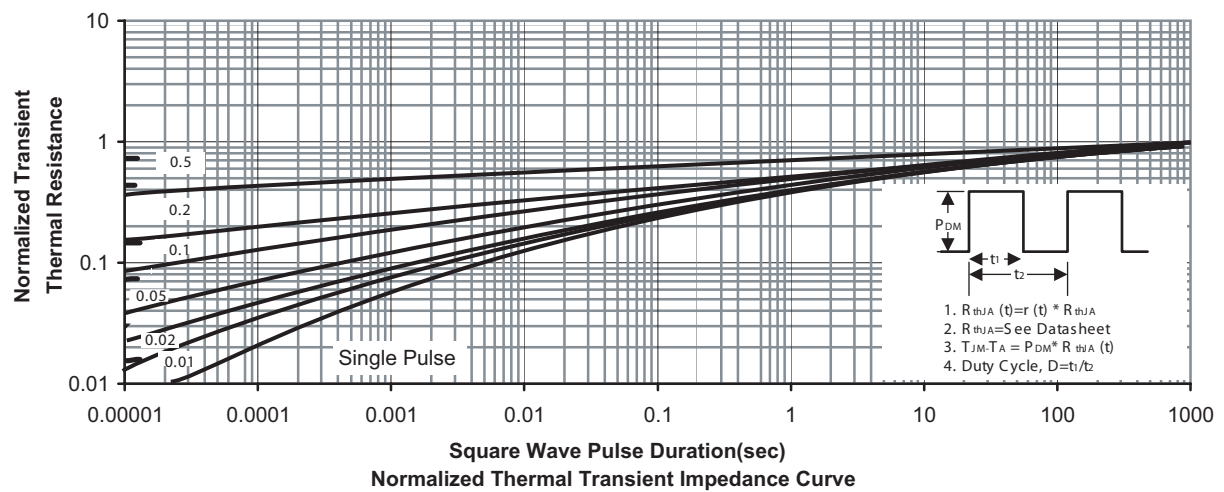
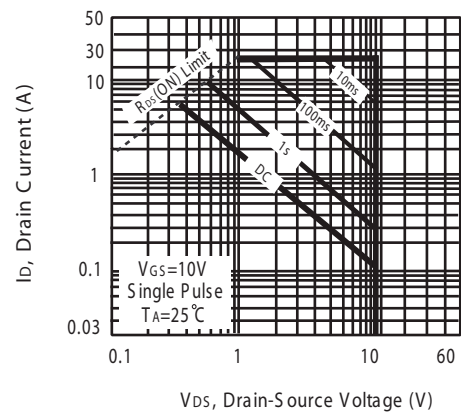
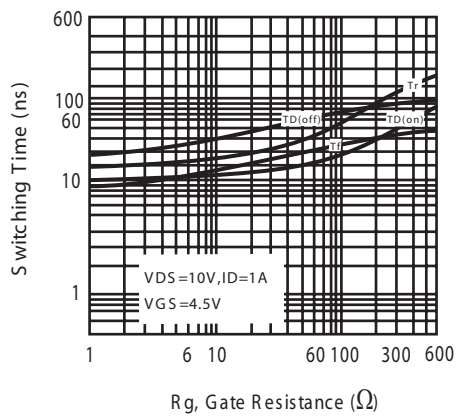
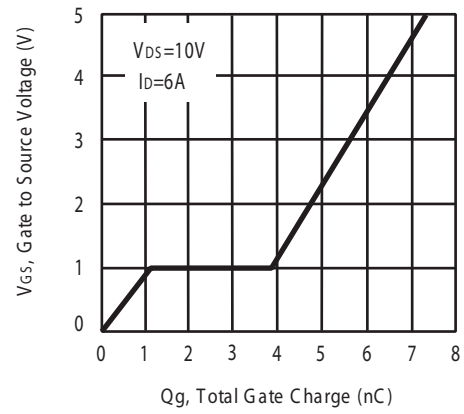
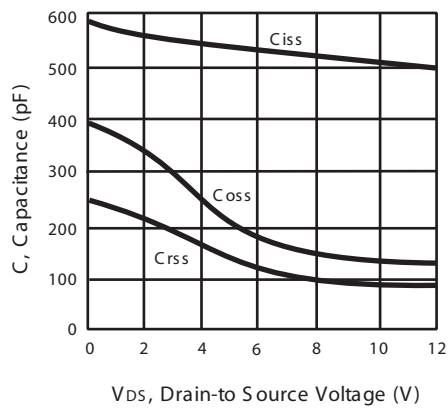


Figure 8. Body Diode Forward Voltage Variation with Source Current

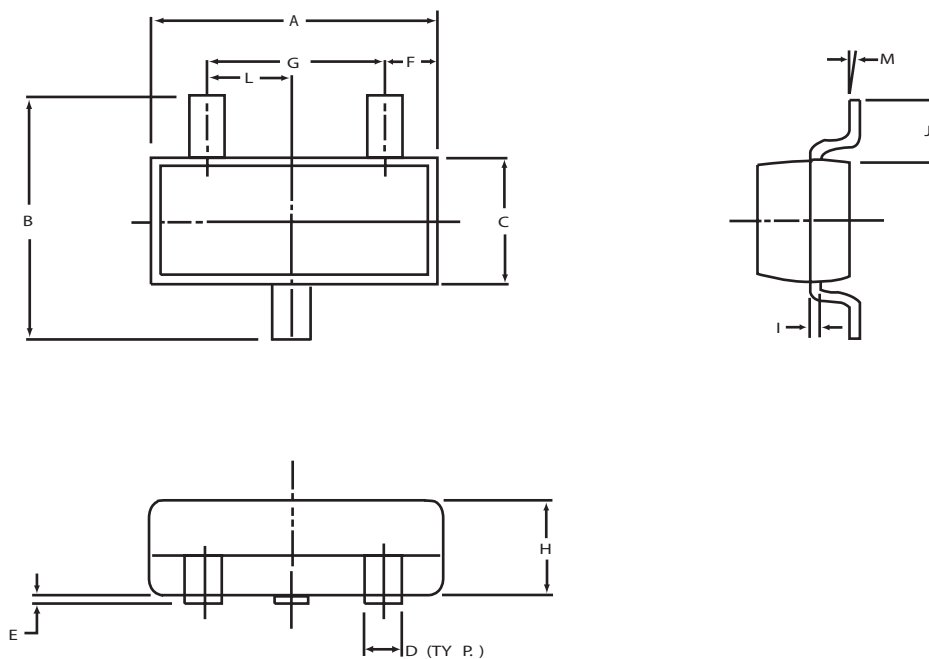
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PACKAGE OUTLINE DIMENSIONS

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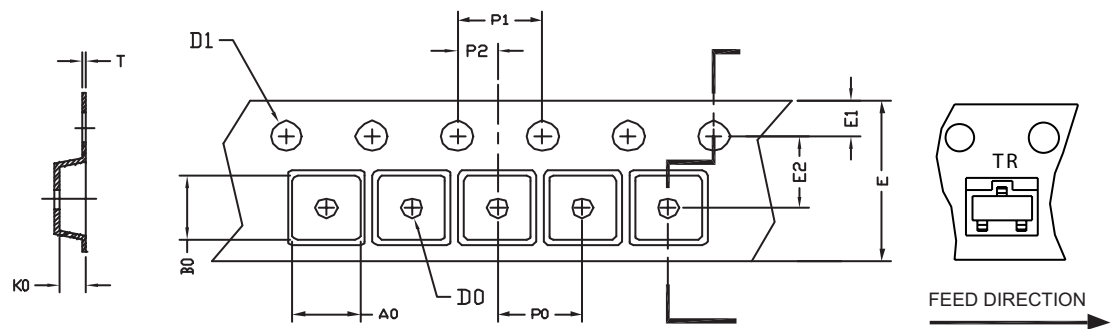


SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.70	3.10	0.106	0.122
B	2.40	2.80	0.094	0.110
C	1.40	1.60	0.055	0.063
D	0.35	0.50	0.014	0.020
E	0	0.10	0	0.004
F	0.45	0.55	0.018	0.022
G	1.90 REF.		0.075 REF.	
H	1.00	1.30	0.039	0.051
I	0.10	0.20	0.004	0.008
J	0.40	-	0.016	-
L	0.45	1.15	0.033	0.045
M	0°	10°	0°	10°

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SOT-23 Tape and Reel Data

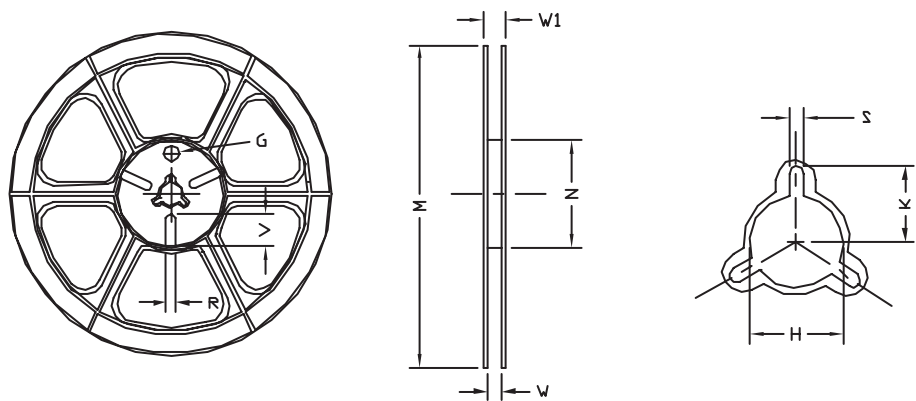
SOT-23 Carrier Tape



UNIT:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
SOT-23	3.20 ± 0.10	3.00 ± 0.10	1.33 ± 0.10	$\phi 1.00$ $+0.25$	$\phi 1.50$ $+0.10$	8.00 $+0.30$ -0.10	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	0.20 ± 0.02

SOT-23 Reel



UNIT:mm

TAPE SIZE	REEL SIZE	M	N	W	W1	H	K	S	G	R	V
8mm	$\phi 178$	$\phi 178$ ± 1	$\phi 60$ ± 1	9.00 ± 0.5	12.00 ± 0.5	$\phi 13.5$ ± 0.5	10.5	2.00 ± 0.5	$\phi 10.0$	5.00	18.00